Record Nr. UNINA9910141285403321 Nonlinear laser dynamics [[electronic resource]]: from quantum dots to **Titolo** cryptography / / edited by Kathy Ludge Pubbl/distr/stampa Weinheim,: Wiley-VCH Chichester, : John Wiley [distributor], c2012 **ISBN** 1-283-64400-2 3-527-63984-5 3-527-63982-9 3-527-63983-7 Descrizione fisica 1 online resource (411 p.) Collana Reviews in nonlinear dynamics and complexity Altri autori (Persone) LudgeKathy Disciplina 621.366 Soggetti Lasers Nonlinear optics Semiconductor lasers Lingua di pubblicazione Inglese **Formato** Materiale a stampa Livello bibliografico Monografia Description based upon print version of record. Note generali Includes bibliographical references and index. Nota di bibliografia Nota di contenuto Nonlinear Laser Dynamics; Contents; Preface; List of Contributors; Part I Nanostructured Devices; 1 Modeling Quantum-Dot-Based Devices; 1.1 Introduction; 1.2 Microscopic Coulomb Scattering Rates; 1.2.1 Carrier-Carrier Scattering; 1.2.2 Detailed Balance; 1.3 Laser Model with Ground and Excited States in the QDs; 1.3.1 Temperature Effects; 1.3.2 Impact

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## Sommario/riassunto

A distinctive discussion of the nonlinear dynamical phenomena of semiconductor lasers. The book combines recent results of quantum dot laser modeling with mathematical details and an analytic understanding of nonlinear phenomena in semiconductor lasers and points out possible applications of lasers in cryptography and chaos control. This interdisciplinary approach makes it a unique and powerful source of knowledge for anyone intending to contribute to this field of research. By presenting both experimental and theoretical results, the distinguished authors consider solitary lase